# Ministry of Higher Education Higher Institute for Engineering and Technology at El-Manzala First semester: 2022/2023 Department: Electronic Engineering. Sheet No. (2) Code: COM113 Course title: fundamental of electronics Examiner: Dr. Mohamed Abdel Rahman

## Answer all of the Following Questions

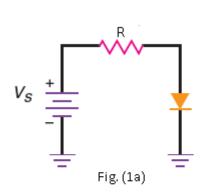
### **Question (1):**

A Full wave rectifier (FWR) is operated from 50Hzsupply with  $E_{s(rms)} = 120 \, \mathrm{V}$ . It is connected to a load drawing  $I_{DC} = 60 \, \mathrm{mA}$  and using  $C = 100 \, \mu\mathrm{F}$  filter capacitor. Calculate the dc output voltage and the root mean square value (rms) of the ripple voltage  $V_{rms}$ . Also calculate the ripple factor  $\gamma$ .(3 marks)

### Question (2):

Aided with the provided I-V characteristics of the diode and the circuit shown in Fig.1, find the diode current and voltage graphically using load line analysis for the following:

 $V_s = 1 V$  and  $R = 20 \Omega$ .



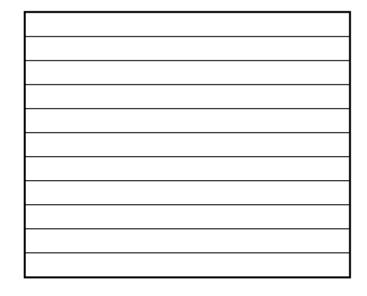


Fig. (1b)

### **Question (3):**

a)	No.	Parameters	Light emitting diode (LED)	Photo diode
	1	function		
	2	Schematic symbol		
	3	Bias for normal operation		
	4	Applications		

# **Question (4):**

- a) Aided with the configurations, sketch a bridge rectifier and demonstrate the output voltage in case of with and without capacitor filter.
- b) An abrupt silicon p-n junction having doping of  $N_A = 10^{18} \, \mathrm{cm}^{-3}$ ;  $N_D = 10^{15} \, \mathrm{cm}^{-3}$  and a circular cross section with diameter of 0.02 inch. Consider  $n_i = 1.5 \times 10^{10} \, \mathrm{cm}^{-3}$  for silicon at room temperature, relative permittivity  $\varepsilon_s = 11.9$  and  $\varepsilon_o = 8.85 \times 10^{-14} \, \mathrm{F/cm}$ .

### Determine the following:

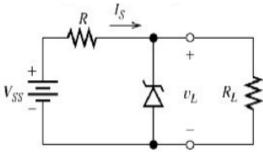
- i) The value of built in voltage  $V_a$ .
- ii) The depletion width in n-region  $x_{no}$ .
- iii) The depletion width in n-region  $x_{DD}$ .
- iv) iv) Total depletion width W<sub>d</sub>.
- v) Sketch the electric field intensity E, charge density  $\rho$  distributions and potential V across the junction.

### **Question (5):**

- a) Draw the zener diode I-V characteristics and label each region.
- b) Consider a zener diode regulator circuit as shown in Fig. 1.

 $V_{SS} = 30 \text{ V}, R = 1.5 \text{ k}\Omega, R_L = 6 \text{ k}\Omega \text{ and } V_Z = 10 \text{ V}.$  Compute the

following:



Fig

i) The current flowing through the load, $I_L$
ii) The source current, $I_s$
i) The zener current I <sub>z</sub> at full load
The zener current 1 <sub>Z</sub> at run load
ii) Power of zener diode $P_z$
iii) Power supplied by the source, $P_s$
v) Output voltage with removing the zener diode